



PULSE TRANSFORMERS, PRODUCTS

CONTENTS:

Technical data regarding Timonta's Pulse Transformers for conventional or SMD mounting. The data sheet contains electrical specifications and mechanical drawings.

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TIMONTA AG

Via San Martino 20 Tel. +41 (91) 646 01 31
CH-6850 Mendrisio Fax +41 (91) 646 26 59
Switzerland

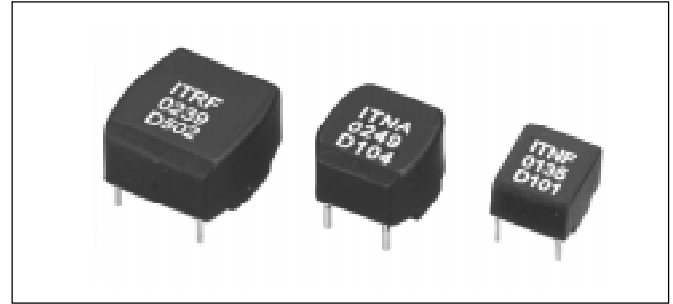
E-Mail: sales@timonta.ch
Internet: <http://www.timonta.ch>

Pulse Transformer for Conventional Board Assemblies



IT Series, Turns Ratio 1:1, 2:1 and 1:1:1

Voltage-time integral $U_s \times T_w$:	150 - 400 V μ s
Pulse rise time T_r :	0.05 - 1.5 μ s
Working voltage:	$U_{eff} \leq 600$ VAC
Partial discharge voltage:	$U_e \leq 1.5 \times U_{eff}$
Climatic category:	25/100/21 acc. to IEC 68-1
Plastic case:	UL 94 V-0
Potting resin:	UL 94 V-0



TIMONTA pulse transformers have been specially developed for the control of semi-conductors in power electronics. Application possibilities are numerous and various and deal mainly with triggering Thyristors, Triacs, power transistors and IGBTs. In most cases there is a suitable model available from the balanced component series for the development of dependable and economical circuits.

The desired specifications are archived through specifically selected materials and well-developed winding technology, and provide the following advantages:

- Electrical separation of circuit and power circuit, with a high insulation rating of at least 3.2 kV between the primary and secondary windings.
- Electrical separation with high insulation rating (at least 500V) between secondary windings.
- Simple circuit layout, since there is sufficient power available to the circuit. This makes special extra provision on the power supply side unnecessary.
- Small coupling capacitances between primary and secondary windings limit transient feedback from the power supply side to the control electronics.
- The defined partial discharge voltage guarantees an effectively unlimited serviceable life.

Technical Data

Description	$\int U dt$ [V μ s]	T_r [μ s]	R_L [Ω]	I_t [A]	R_p [Ω]	R_s [Ω]	C_c [pF]	U_{isol} [kV~]	$P_m^{(1)}$ [W]	Case	Turn ratio [N]	L_s [mH]	Application
ITNA-0235-D103	200	0.9	100	0.1	1	1	20	3.5	0.5	35 - 3	1 : 1	2.8	Universal
ITRA-0235-D103	200	0.05	100	0.1	2	1	80	3.2	0.5	35 - 3	1 : 1	2.8	$T_R \leq 0.05 \mu s$
ITNA-0249-D104	300	1	100	0.1	0.8	0.8	20	3.5	0.7	49 - 3	1 : 1	3.5	Universal
ITRA-0249-D104	300	0.05	100	0.1	0.8	0.8	90	3.2	0.7	49 - 3	1 : 1	3.5	$T_R \leq 0.05 \mu s$
ITNA-0239-D202	400	1	60	0.17	0.4	0.4	20	3.5	1.0	39 - 3	1 : 1	2.2	Universal
ITRA-0239-D502	400	0.1	20	0.5	0.4	0.4	100	3.2	1.0	39 - 3	1 : 1	2.2	$T_R \leq 0.1 \mu s$
ITNB-0249-D101	250	1	100	0.1	1.0	0.5	20	3.5	0.7	49 - 3	2 : 1	1.4	Universal
ITRB-0249-D101	250	0.05	100	0.1	1.0	0.5	70	3.2	0.7	49 - 3	2 : 1	1.2	$T_R \leq 0.05 \mu s$
ITNB-0239-D202	350	1.5	60	0.17	0.8	0.4	20	3.5	1.0	39 - 3	2 : 1	1.6	Universal
ITRB-0239-D502	350	0.5	20	0.5	0.8	0.4	90	3.2	1.0	39 - 3	2 : 1	1.6	$T_R \leq 0.5 \mu s$
ITNF-0135-D101	150	0.9	100	0.1	0.5	0.5	10	3.5	0.5	35 - 4	1 : 1 : 1	1.1	Universal
ITRF-0235-D101	150	0.05	100	0.1	1	0.5	40	3.2	0.5	35 - 4	1 : 1 : 1	1.1	$T_R \leq 0.05 \mu s$
ITNF-0249-D101	250	1	100	0.1	0.5	0.5	20	3.5	0.7	49 - 4	1 : 1 : 1	1.4	Universal
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Table data at ϑ_a 25°C

(1) $P_m @ \vartheta_a$ 50°C; Power derating over 50°C: $P = P_m \times (100 - \vartheta_a) / 50$

On request, models with other turn ratios are available

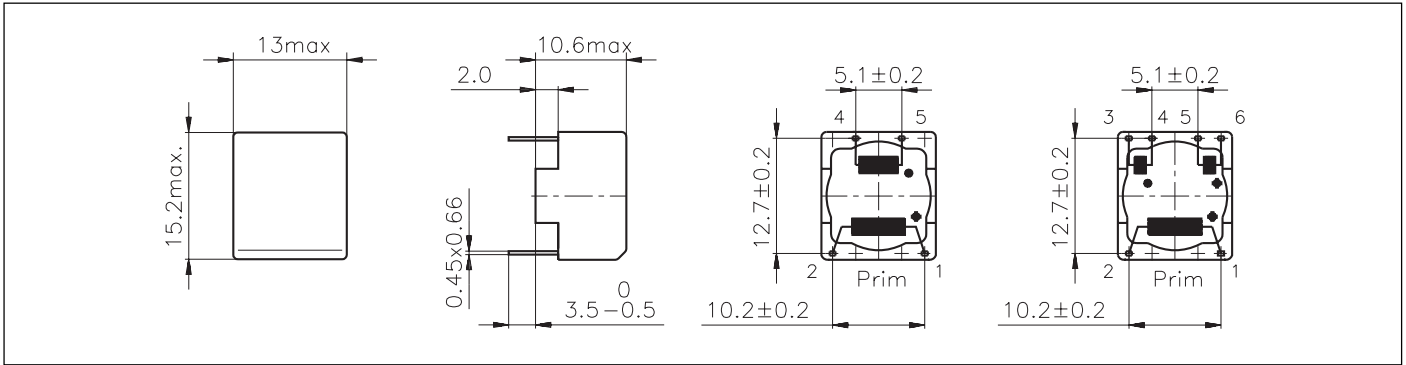
Conventional Cases



Case 35

35-3

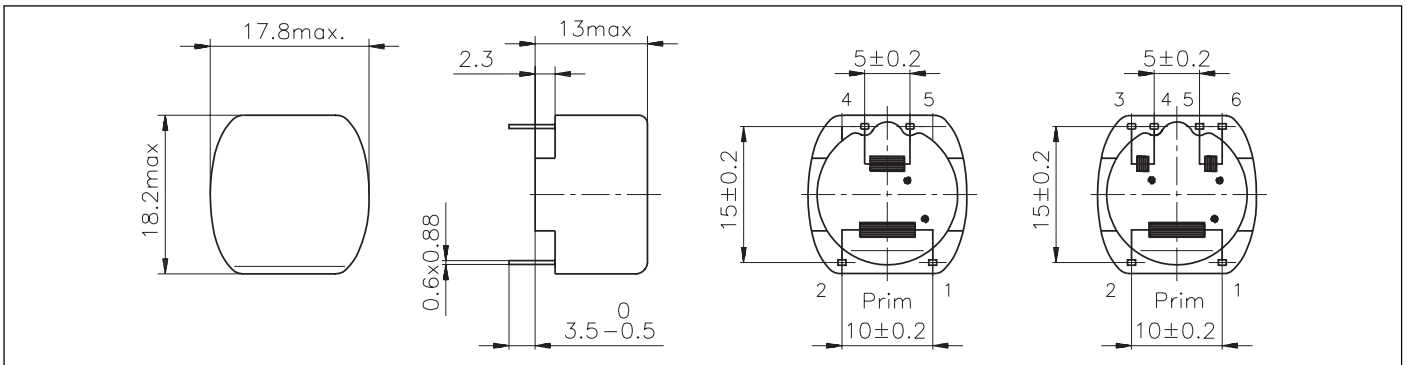
35-4



Case 49

49-3

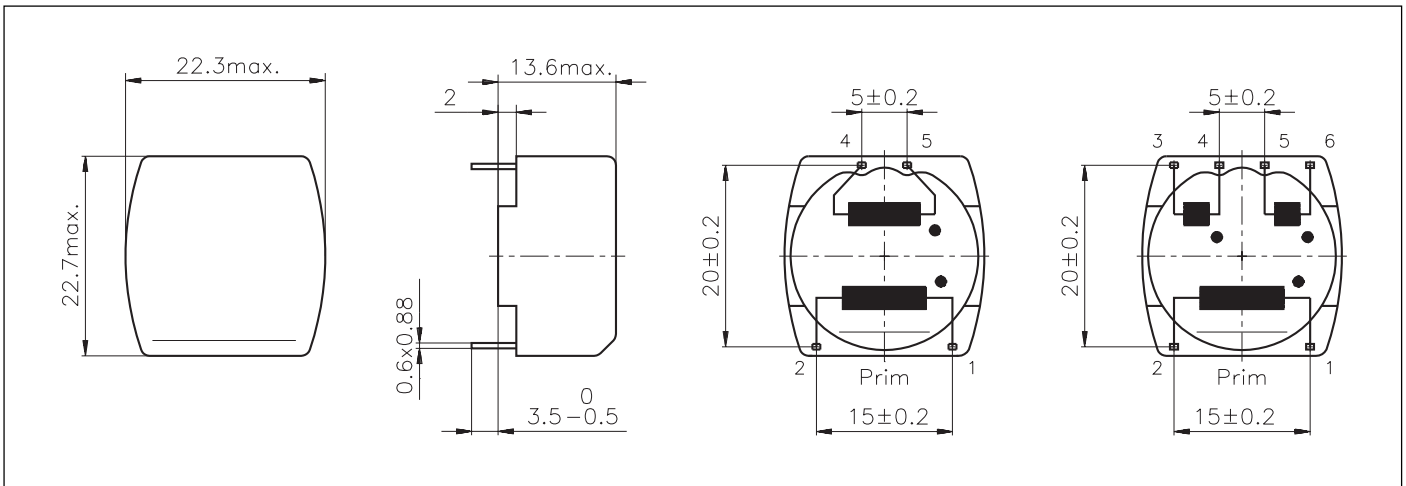
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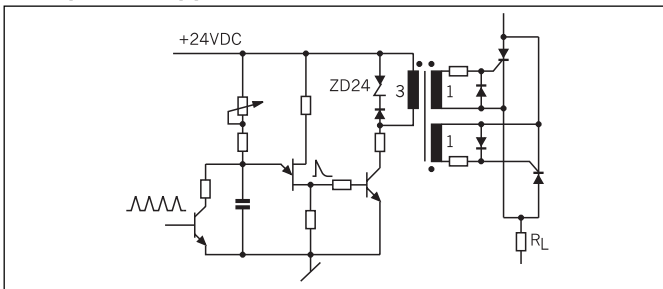
Case 39

39-3

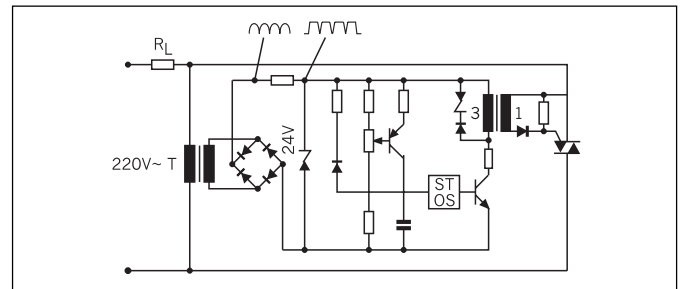
39-4



Examples of applications



Firing of antiparallel Thyristors (SCR's) by means of unijunction and transistor amplifiers



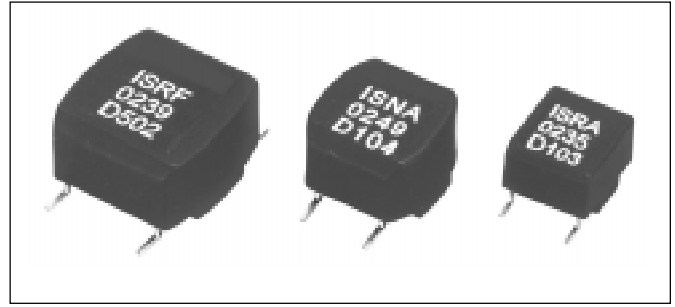
Triac phase angle control

Pulse Transformers for SMD-Assemblies



IS Series, Turns Ratio 1:1, 2:1 and 1:1:1

Voltage time integral $U_s \times T_w$:	150 - 400 V μ s
Pulse rise time T_r :	0.05 - 1.5 μ s
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Table data at ϑ_a 25°C

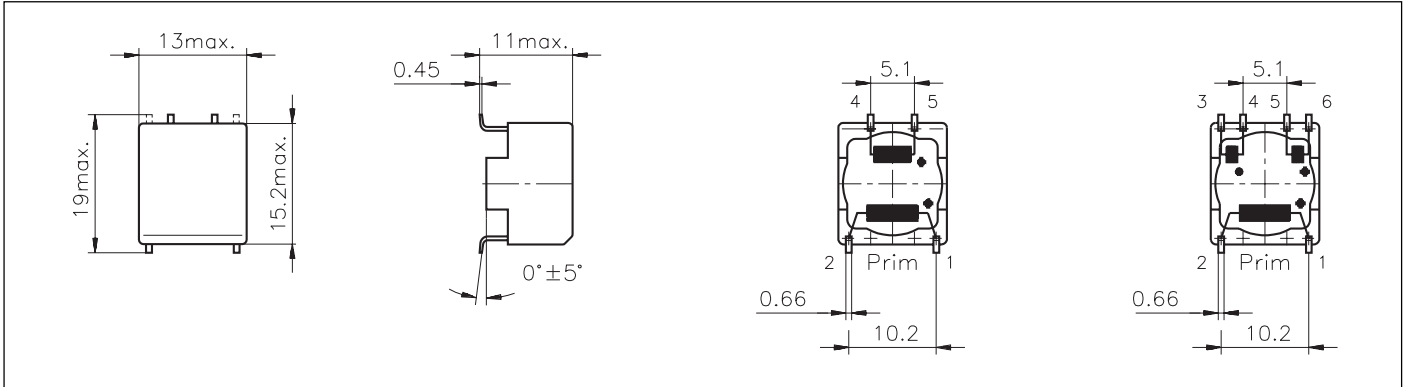
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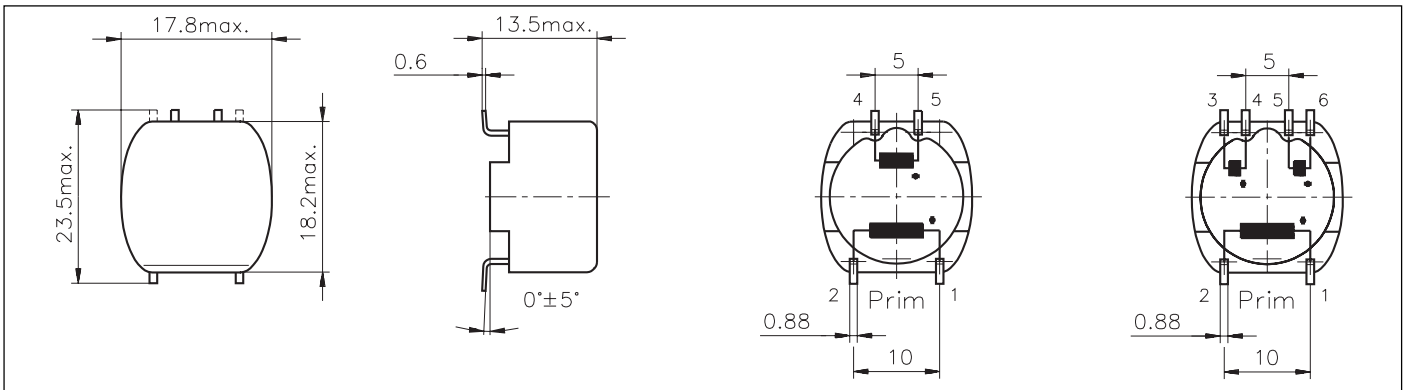
Case for SMD mounting



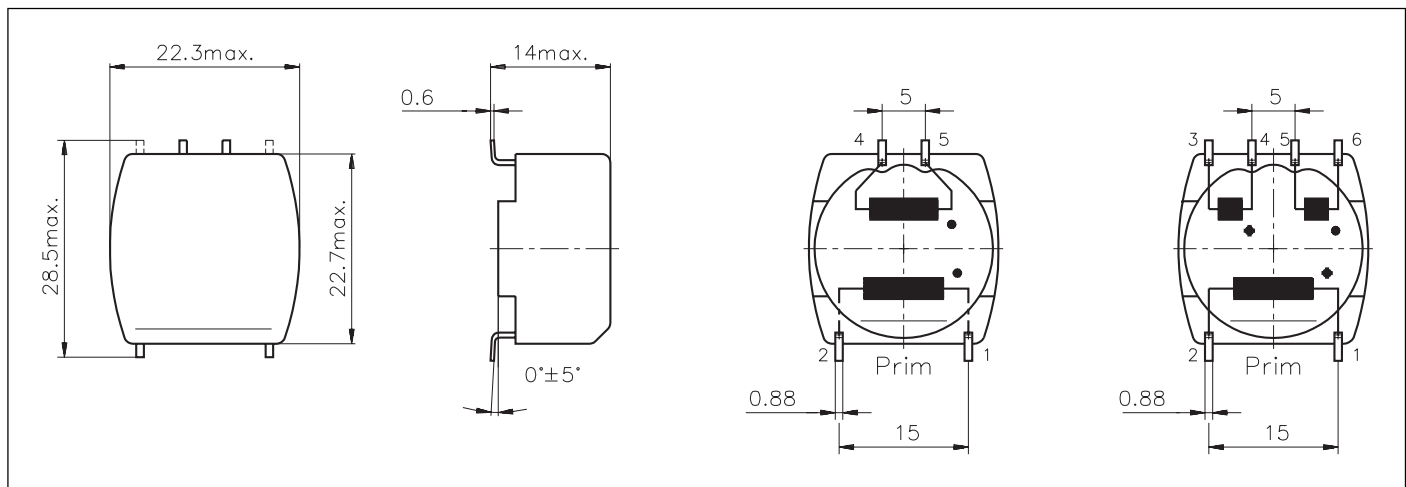
Case 35S



Case 49S



Case 39S



Possible solder land pattern for SMD mounting

Case 35S

